

U. S. Appl'n. No. 10/814,813

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REMARKS

Reconsideration of the application is respectfully requested in view of the proposed amendments to the claims and the discussion presented below. The proposed amendments are supported by the application as filed and no new matter has been added by any of the amendments.

The Examiner is respectfully requested to enter the proposed amendments because they would be proper under 37 C.F.R. § 1.116(b)(1) ("[a]n amendment may be made canceling claims or complying with any requirement of form expressly set forth in a previous Office action"). It is believed that entry of the proposed amendments, in which claim 1 is cancelled and claims 2 and 6 are amended to overcome a rejection based on form, will place this application in condition for allowance.

The Examiner also is respectfully requested to enter the proposed amendments because they would be proper under 37 C.F.R. § 1.116(b)(2) ("[a]n amendment presenting rejected claims in better form for consideration on appeal may be admitted"). It is believed that the cancellation of claim 1 and the proposed amendments to claims 2 and 6 to overcome the indefiniteness rejection, will present the pending claims in better form for appeal.

In addition, the proposed amendments are believed to be proper under 37 C.F.R. § 1.116(b)(3) ("[a]n amendment touching the merits of the application or patent under reexamination may be admitted upon a showing of good and sufficient reasons why the amendment is necessary and was not earlier presented"). The Examiner located and cited new references (Ho and Emori) against the pending claims.

If the proposed amendments are entered, claim 1 will be cancelled and claims 2 and 6 will be amended. Claims 2-11 will then be present in the application.

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Furthermore, the Applicants submit a substitute specification and abstract pursuant to 37 C.F.R. 1.125. The substitute specification and abstract corrects a number of minor, mostly grammatical, errors in the original specification so that the application will be in fit condition for allowance and issue. The errors are so dispersed through the original specification and abstract that submission of a substitute specification and abstract is believed to be more appropriate than amending individual paragraphs in the specification. The substitute specification and abstract include no new matter.

This paper is being filed within two months of the mailing date of the final office action. The benefit of the procedure for calculating the expiration of the shortened statutory procedure set forth in M.P.E.P. 706.07(f) ("Time for Reply to Final Rejection") is claimed.

Discussion

The Examiner is thanked for allowing claims 3, 4, and 7-11.

The Examiner rejected claim 1 as being anticipated separately by Ho and Emori. Claim 1 is proposed to be cancelled without prejudice.

The Examiner rejected claims 1, 2, 5, and 6 under 35 U.S.C. 112, second paragraph as being indefinite. The Examiner indicated that claims 2, 5, and 6 would be allowable if rewritten to overcome the rejections for indefiniteness and to include all of the limitations of the base claim and any intervening claims.

Claim 1 is proposed to be cancelled without prejudice. Claim 2 is proposed to be amended to overcome this indefiniteness rejection by adding an actuator and to include the limitations of the base claim 1. The proposed amendments to claim 2 are believed to overcome the rejection of claim 5. Claim 6 is proposed to be amended to overcome the indefiniteness rejection and change its dependence from claim 1 to claim 5.

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Conclusion

Claims 2 and 6 should be amended as proposed above in order to put this application in condition for allowance or in better condition for appeal. The substitute specification and abstract should be accepted. The Applicants submit that the application then will be in condition for allowance and respectfully urge the Examiner to pass this case to issue. The Examiner is respectfully invited to telephone the undersigned attorney as needed in order to advance the examination of this application.

* * *

The Commissioner is authorized to charge any additional fees which may be required or credit overpayment to deposit account no. 12-0415. In particular, if this response is not timely filed, then the Commissioner is authorized to treat this response as including a petition to extend the time period pursuant to 37 CFR 1.136 (a) requesting an extension of time of the number of months necessary to make this response timely filed and the petition fee due in connection therewith may be charged to deposit account no. 12-0415.

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I hereby certify that this correspondence is being transmitted by facsimile to the United States Patent and Trademark Office (USPTO) on the date shown below. Specifically, this correspondence is being telefaxed to Examiner Dougherty at the USPTO at 571-273-8300 on

June 23, 2006

(Date of Transmission)

Aileen M. Shrestha


(Name of Person Signing)



(Signature)

June 23, 2006

(Date)



R. Dabney Eastham

Attorney for Applicants

Reg. No. 31,247

LADAS & PARRY

5670 Wilshire Boulevard, Suite 2100

Los Angeles, California 90036

(323) 934-2300

(323) 934-0202 facsimile

reastham@ladas.com

[Substitute specification for U.S. application 10/814,813 – marked up-version]

METHOD OF ENLARGING A TRAVEL OF PIEZOELECTRIC SENSOR AND MEMS SWITCH EMPLOYING THE SAME

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention relates to a MEMS switch employing a piezoelectric sensor, and more particularly, to a method of enlarging a travel of a piezoelectric sensor and a MEMS switch employing the enlarged travel of a piezoelectric sensor.

2. Description of the Related Art

Conventionally, a micro-electromechanical systems (MEMS) switch can be classified by means of an employed actuator into four types, such as dynamo-electrostatic, thermal expansion, dynamo-electromagnetic and piezoelectric types, and by means of a switching direction into two types, such as vertical contact and lateral contact types.

Firstly, the dynamo-electrostatic type of MEMS switch uses a curved surface electrode type or comb drive type[1]. This kind of switch is ~~which are~~ mostly developed nowadays. This type of MEMS switch employs the principles that two electrodes are contacted when different polarity of voltages are applied to the two

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electrodes of which one is a stationary electrode and the other is a movable electrode spaced apart from the stationary electrode.

Generally, the manufacture of this type of switch is not difficult ~~in the process~~; however, it additionally needs the use of a chip for raising the voltage to ~~adopt~~ be useful for the current RF device devices due to the requirement of at least several decades of voltage, thereby increasing the manufacturing cost. The travel ~~Travel~~ speed of the switch has a range of 1 to 200 seconds depending upon its structure.

Secondly, the dynamo-electromagnetic type of MEMS switch uses the theory of an electromagnet, which makes a magnetic field through a coil structure. While this type of switch can be operated by a relatively low voltages of about 5 Volts, when the structure of the switch becomes complex and huge, its power consumption comes to reach a number of hundreds mW.

The thermal expansion type of MEMS switch uses the theory that the volume of solid or liquid materials expands as its temperature increases. While a relatively low voltage of about 5 Volts can also operate this type of switch, this switch is very sensitive to an ambient temperature, its power consumption comes to reach a number of hundreds of mW, and conclusively its travel speed is too slow such that it becomes several decades of milli-seconds.

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The piezoelectric type of MEMS switch uses the theory of piezoelectric materials of which volume is expanded when a voltage is applied. While this type of switch ~~[[have]]~~ has the most prompt travel speed (100 nsec to 1 sec) among the abovementioned methods, the most large power can transmit when it drives, and, while it can be driven by a relatively low voltage, this strain can be a maximum of 0.1% of the length of the materials, thus, the use of the MEMS switch has a disadvantage that its travel length is no more than several decades or hundreds of nanometers.

In this connection, the raising of the operation voltage implies difficulties in adoption of a portable optical communication device or personal communication services, or the requirement of additional cost due to the use of the voltage-raising device.

High level of power consumption means the reduction of working period per one charge of ~~portable~~ portable devices such as PCS, laptop computer, etc. The more the speed of data communication is accelerated, the more the need of the component having a prompt travel speed is increased. Further, in RF applications such as PCS, laptop, WLAN etc., in which various ~~researches~~ approaches for integrating all components in one chip are accomplished, those skilled in the art are interested in MEMS components having a relatively small area.

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MEMS is a technology of combining a computer and a very small mechanical device such as a sensor, a valve, a gear, a reflection mirror and a driver etc. mounted in the semiconductor chip. It is used as a vibration accelerator in an air-bag for an automobile. A MEMS device comprises a micro circuit on a very small silicon chip which a part of mechanical devices have been manufactured.

Further examples of ~~Example~~ applications of MEMS include GPS sensor sensors for tracking express parcel services and detecting a intermediate parcel treatment process; a sensor mounted on wings of an airplane provided with a number of tiny auxiliary ~~aileron~~ ailerons for detecting and reacting to air flow depending upon variations of surface resistance of the wings of an airplane; and optical exchanging devices capable of exchanging optical signals to an individual passageway at a speed of 20 nsec.

As described hereinabove, while the piezoelectric type MEMS switch is capable of nearly solving the aforementioned problems since it allows a lowering of voltage and power consumption, and a raising of travel speed, since a travel length ~~[[of]]~~ for a voltage below 5 volts is too small, it is impossible to apply the variable optical device such as optical switch, RF switch, filter, etc.

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Eventually, the present invention provides a method of enlarging a travel length of the piezoelectric materials while its travel mechanism using a piezoelectric material is used as ~~ever~~ before.

SUMMARY OF THE INVENTION

The present invention provides a method of enlarging a travel length of the piezoelectric materials to utilize the abovementioned advantage of the piezoelectric materials to the utmost and to solve the disadvantage of the limited travel length.

It is an object of the present invention to provide a method of enlarging a travel length of piezoelectric materials and a MEMS switch employing the enlarged travel length of piezoelectric materials by means of enlarging a nano-level of travel length up to at least about 10 times for using it as a switch device.

It is another object of the present invention to provide a MEMS switch employing means for enlarging a travel length of the piezoelectric materials, wherein the electrode is a lateral contact type, since a switching operation of the piezoelectric material has a relatively high switching pressure and stiffness to the lateral direction in comparison with the vertical direction.

A core technology of the present invention is a technique of enlarging the travel of the piezoelectric materials by using a leverage theory when ~~it drives~~ the

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piezoelectric materials are driven with a potential difference applied by an actuator, and increasing the stiffness and switching pressure of the switch by employing the lateral contact type.

In accordance with the present invention, it is capable of enlarging the travel length of the piezoelectric materials about ~~decuple~~ a decade to allow ~~the~~ their use as switching means and the substitution of a linear MEMS switch for a non-linear semiconductor device such as pin diode or MOSFET, thereby decreasing the amount used of filters for linear characteristics, and promoting the properties of isolation and insertion loss.

As described above, the switch, employed by a wireless LAN, etc., in accordance with the present invention is a non-linear semiconductor device such as pin diode or MOSFET.

If a linear MEMS switch could substitute for it, it is capable of decreasing the amount used of filters and power consumption, and promoting the properties of isolation and insertion loss.

The MEMS switch, as described above, can be classified by means of an employed actuator into four types, such as dynamo electrostatic, thermal expansion, dynamo-electromagnetic and piezoelectric types, and by means of a switching direction into two types, such as vertical contact and lateral contact

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types. (Reference: Lee, Hoyoung, RFMEMS Switch, Korean Electronics Technology Institute, Electronic Information Center, 2002, /G. M. Rebeiz and J-B. Muldavin, RF MFA4S switches and switch circuits, IEEE Microwave magazine, pp. 59-71, Dec. 2001./ Elliott R. Brown, RF-MEMS Switches for ~~reconfigurable integrated circuits~~ Reconfigurable Integrated Circuits, IEEE Trans. on Microwave ~~theory and tech~~ Theory and Tech, v.46, n.11. Nov, 1998.)

Conventionally, in the classification according to a switching method, the most currently used MEMS switch is the vertical contact type since the manufacture of a lateral electrode for lateral contact of the switch is difficult ~~[[in]]~~ using the current semiconductor process. The present invention ~~employed~~ employs the lateral contact type switch as a manufacturing technique of the lateral electrode is developed more and more. The reason for employment of the lateral electrode is that it has a ~~[[high]]~~ higher switching pressure and stiffness ~~[[more]]~~ than the vertical electrode. (Reference: Ezekiel J. J. Kruglick, Kristofer S. J. Pister, Lateral MEMS ~~microcontact considerations~~ Microcontact Considerations, J. of MEMS, v.8, n.3, September 1999./ Ignaz Schiele and Bernd Hillerich, Comparison of ~~lateral and vertical switches for application as microrelays~~ Lateral and Vertical Switches for Application as Microrelays, J. Micromech. Microeng., pp 146-150, 1999.)

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BRIEF DESCRIPTION OF THE DRAWING

These and other features, aspects, and advantages of preferred embodiments of the present invention will be more fully described in the following detailed description, taken in connection with the accompanying drawing. In the drawing:

Fig. 1 is a plan view showing a means for enlarging of the travel length of a piezoelectric sensor of the present invention.

DESCRIPTION OF THE PREFERRED EMBODIMENT

Hereinafter, the details of a method of enlarging a travel of piezoelectric sensor and a MEMS switch thereof will be described in connection with the accompanying drawing.

As shown in Fig. 1, the MEMS switch of the present invention is provided with a piezoelectric sensor 10 having first electrode P at its one end, an actuator 11 connected to the piezoelectric sensor 10 at its one end of the actuator 11, and means 12 for enlarging the travel of the piezoelectric sensor 10, having second electrode P to face the first electrode at its one end, which is connected to the other end of the actuator 11 and elastically attached to the other end of the sensor 10 at its other end.

A method of enlarging a travel of the piezoelectric sensor 10 comprises the steps of:

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firstly, shrinking the actuator 11 ~~piezoelectric sensor 10~~ by applying a potential difference,

secondly, enlarging the travel of the actuator 11 ~~sensor~~ through the enlarging means 12,

thirdly, switching the lateral contact switch by contacting the electrode P by installing the switching electrode to a lateral side of the piezoelectric sensor 10 material.

The above steps of the method of the present invention will be described more specifically as follows.

Firstly, the piezoelectric sensor 10 shrinking step uses the phenomenon that the piezoelectric material is shrunk when the potential difference is applied to the piezoelectric material through the actuator 11. In case of the conventional piezoelectric material having a maximum strain rate of about 0.1%, a piezoelectric material of 100 nm lengths has a strain displacement of 0.1 nm.

Therefore, the strain displacement of the piezoelectric materials becomes a base of driving force, and it is required that the above strain displacement is enlarged up to a sufficient level.

Secondly, in the enlarging step, the strain displacement is enlarged by the travel enlarging means 12 provided with a lever. Since the displacement is too

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small to be employed in a variable optical device such as an optical filter, optical switch, etc., and the use of a relatively big piezoelectric sensor for a large displacement results in an abandonment of the advantage of the MEMS switch, the enlargement of the displacement in a small structure is required. Therefore, the present invention provides ~~[[the]]~~ a travel enlarging means capable of providing at least 10 times of ~~[[a]]~~ travel enlargement by using the leverage theory.

Thirdly, in the switching step, when the electric charge is applied to the piezoelectric sensor 10 through the actuator 11, the switch becomes "On" as the lateral electrodes P ~~[[is]]~~ are contacted with each other. When the electric charge is removed from the piezoelectric sensor 10, the lateral electrodes P are ~~contact~~ ~~portion~~ is separated by an elastic recovering force of the leverage, thereby making the switch ~~[["Off".]]~~ "Off."

As described hereinabove, the present invention provides a MEMS switch capable of using a relatively low voltage less than 5V, lowering ~~[[a]]~~ power consumption, embodying a MEMS switch having ~~[[an]]~~ excellent linear characteristics, embodying a switch having a low isolation and insertion loss, and applying to wide range of wireless communication such as PCS, wireless LAN etc.

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While only a specific embodiment of the present invention have has been described above, it will occur to a person skilled in the art that various modifications can be made within the scope of the appended claims.